Photon energy dependence of graphitization threshold for diamond irradiated with an intense XUV FEL pulse

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We studied experimentally and theoretically the structural transition of diamond under an irradiation with an intense femtosecond extreme ultraviolet laser (XUV) pulse of 24–275 eV photon energy provided by free-electron lasers. Experimental results obtained show that the irradiated diamond undergoes a solid-to-solid phase transition to graphite, and not to an amorphous state. Our theoretical findings suggest that the nature of this transition is nonthermal, stimulated by a change of the interatomic potential triggered by the excitation of valence electrons. Ultrashort laser pulse duration enables to identify the subsequent steps of this process: electron excitation, band gap collapse, and the following atomic motion. A good agreement between the experimentally measured and theoretically calculated damage thresholds for the XUV range supports our conclusions.

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It is often observed that a femtosecond irradiation of a material induces an atomic disorder therein: amorphization, or defect creation. Graphitization of diamond is a counterexample as it is an order-to-order (solid-to-solid) phase transition. It illustrates the fundamental interplay between the bonding, interaction, electron excitation and heating, which are driving free electrons does not occur. As a result, the first stage of the process adds data for the phase-transition fluence threshold and an understanding of the response of diamond to intense XUV .

In the XUV and x-ray domain the excitation of electrons is only due to single photon absorption, and the absorption by free electrons does not occur. As a result, the first stage of the interaction, electron excitation and heating, which are driving nonthermal processes, is quite different compared to the optical regime.1 It is then questionable if a nonthermal phase transition can be triggered by an XFEL pulse. In the present Rapid Communication we identify the phase transition, which diamond undergoes under femtosecond XUV irradiation, as the graphitization. We show that the final state of the material is nonthermal. In the XUV and x-ray domain the excitation of electrons is only due to single photon absorption, and the absorption by free electrons does not occur. As a result, the first stage of the interaction, electron excitation and heating, which are driving nonthermal processes, is quite different compared to the optical regime.1 It is then questionable if a nonthermal phase transition can be triggered by an XFEL pulse. In the present Rapid Communication we identify the phase transition, which diamond undergoes under femtosecond XUV irradiation, as the graphitization. We show that the final state of the material is nonthermal.

In addition to this fundamental aspect, understanding the graphitization process is technologically relevant as diamond, with its different forms ranging from bulk, thin film,3 to nano-objects,4 is increasingly used for practical applications. As a result, graphitization, i.e., stability of diamond, upon annealing,5,6 high pressure,7,8 and irradiation by an ultrafast optical laser9,10 has been investigated, both experimentally and theoretically. The work presented in this Rapid Communication adds data for the phase-transition fluence threshold and an understanding of the response of diamond to intense XUV.

A first step to investigate this challenging issue was recently made in Ref. 11 with the development of a new theoretical hybrid model for the interaction of femtosecond XUV laser pulses with solids. The dynamics of the irradiated diamond
is modeled by combining a nonequilibrium description of the ultrafast electronic excitation and relaxation with the atomic dynamics on a transient collective potential energy surface. For each transient atomic position, the new electronic band structure is also calculated. Such a combination allows us to follow any phase transition whether it is thermally or nonthermally activated. We use this model to describe the details of the XUV photon-induced phase transition of diamond for four different photon energies, including a prediction of the graphitization threshold.

For our analysis, we place the atoms initially on their equilibrium positions corresponding to the diamond structure, and assign to them velocities corresponding to room temperature. At room temperature, diamond has a band gap of $\sim 5.5$ eV. This large band gap assures that there are nearly no conduction band electrons. After we let the atoms thermalize, i.e., establish a Maxwellian velocity distribution, we expose the simulation box to a laser pulse with a Gaussian intensity envelope of 50 fs full width at half maximum (FWHM).

Figure 1 shows that the electron density within the conduction band increases, following photoabsorption and secondary impact ionization. This affects the atomic dynamics, and the electronic band structure. The band gap starts shrinking, as can also be observed in Fig. 1. Shrinkage of the band gap promotes more electrons from the valence to the conduction band, further enhancing the increase of conduction band electron density. Almost independently of the particular photon wavelength within the range from 24 to 275 eV, the band gap collapses within $\sim 40-50$ fs after the maximum of the laser pulse. This is accompanied by a further increase of the free-electron density. After this time, the electronic structure is already close to the one of graphite, rather than to the one of diamond.

The collapse of the band gap, and the corresponding increase of the conduction band electrons, changes the interatomic bonding. The atoms are affected by a new potential energy surface and move towards the new equilibrium positions, corresponding to the graphite phase.

This can be seen in Fig. 2, where the mean nearest neighbor distance is plotted as a function of time for different photon energies but at the same absorbed dose. One can see that shortly after the exposure, the diamond starts expanding. Later, following the band gap collapse at $\sim 40-50$ fs (compare Fig. 1), the relocation of atoms from diamond to graphite positions begins. It finishes within the next 40–50 fs. Thus, within $\sim 80–100$ fs after XUV exposure, the irradiated diamond turns into graphite through nonthermal relaxation. The calculated atomic positions of the final state of the matter exactly correspond to the positions of graphite. The atomic positions obtained from the simulations clearly evidence a direct solid-to-solid phase transition, with no intermediate liquid state. Similar time scales for a nonthermal solid-to-liquid transition in graphite were recently reported in Ref. 13.

We have also calculated the dynamics of the irradiated diamond for different fluences, in order to identify the fluence threshold for graphitization. We find that the phase transition occurs when the conduction electron density overcomes a threshold value of $\sim 1.5\%$ of the total number of valence electrons. When this occurs, the band gap collapses quickly and induces a further increase of the electron density, up to $\sim 3\%$. This initiates the nonthermal phase transition. For all considered photon energies, i.e., 24, 91, 177, and 275 eV, the threshold has the same value of an absorbed energy of 0.7 eV/atom. We conclude that this value is valid for the entire photon energy range between 24 and 275 eV.

In order to test this model, we have measured the graphitization thresholds experimentally. The experiments were performed at two different XFEL facilities: The experiments...
with 24 eV photon energy were performed at the SPring-8 Compact SASE Source in Japan (SCSS) while the ones at 91, 177, and 275 eV photon energies were performed at the Free Electron Laser in Hamburg (FLASH) in Germany. Both facilities deliver pulses of duration within the 30–80 fs range. For all experiments, an experimental procedure was followed, which is described in detail in Ref. 14. The samples, consisting of chemical-vapor-deposited (CVD) diamonds, were placed in the focus of the focusing optics and exposed to a single XFEL pulse at normal incidence. The energy of each pulse was measured. The samples were analyzed ex situ using different techniques. First, each irradiated area was measured using a differential interference contrast (DIC) optical microscope (see the images in Fig. 3). This technique enables to measure any change of the optical refractive index and allows measuring the area of the x-ray induced modification. The measured areas are then plotted as a function of the impinging fluence. The experimental points are fitted down to 0, i.e., no damage, which allows determining the phase-transition threshold fluence.

To gain a deeper insight in the effect of irradiation, micro-Raman spectroscopy measurements (λ = 514.5 nm laser, resolution <4 cm⁻¹) were performed on selected spots. Raman spectroscopy is a well-established technique, allowing measurements to be performed on a small surface (2 μm spot diameter) and can unquestionably identify diamond and graphite phases. The red curve in Fig. 3 corresponds to the nonirradiated diamond sample and shows the typical peak of diamond at 1332 cm⁻¹. The black curves correspond to the irradiated area at the center of the spot shown in the DIC pictures in Fig. 3. The Raman spectra feature two peaks located at 1575 cm⁻¹ (G peak) and 1355 cm⁻¹ (D peak). The G peak is related to the degenerate transverse and longitudinal optical phonon mode of graphite, while the D peak is related to defects in the graphite structure. The fact that both G and D peaks are clearly distinct indicates that the irradiation leads to graphite and not an amorphous structure. Moreover, the intensity ratio of G and D peaks is related to the size of the graphite crystallites. An ongoing quantitative analysis of this ratio as a function of the impinging fluence shows that the size of the resulting graphite crystals is limited to a few nanometers. The high strain energy at the diamond/graphite surface is responsible for this size limitation, as in the case of thermally activated graphitization.

The graphitization energy threshold is retrieved by extrapolating the DIC versus pulse energy data points down to zero. The full procedure is described in Ref. 14. The energy considered was the total energy arriving on the sample, i.e., taking into account the whole beamline transmission. In order to determine the fluence threshold, an estimate of the beam area is needed which is nontrivial as XFEL beam profiles are generally non-Gaussian. The effective area A_eff, which is equivalent to the area at the 1/e level of a Gaussian beam, was determined by using a specific method described in detail in Ref. 16. Finally, the fluence threshold for graphitization is retrieved for each photon energy and is shown in Fig. 4. The larger error bar for the 275 eV value is due to the uncertainty in the photon energy inducing a large uncertainty about the beamline transmission and impinging pulse energy, as explained in detail in Ref. 17.

The simulations predict a graphitization threshold of 0.7 eV/atom, which is assumed to be valid for the energy range from 24 to 275 eV. In order to compare to the measured values, the dose has to be converted to fluence, which is achieved by taking into account the different photoabsorption cross sections of diamond provided in Refs. 18–21. The threshold predicted by theory is then represented in Fig. 4 by the continuous lines.

The measured thresholds are very close to the theoretical curves. This good agreement supports the validity of the model, and seems to indicate that the observed graphitization induced by XFEL pulses results from a nonthermal phase transition.

In conclusion, we have demonstrated, both experimentally and theoretically, that diamond undergoes a phase transition to graphite under XUV femtosecond irradiation. The simulations...
support the hypothesis of a nonthermal activation of the phase transition. In the framework of this model, we found that this transition proceeds as a multistep process. When the absorbed energy is high enough (>0.7 eV/atom), the conduction electron density reaches ~1.5%. Such an electron density induces a band gap collapse. In turn, the electron density is further increased up to ~3%. This stimulates interatomic bond breaking, resulting in the phase transition. As the lattice temperature increases only after material modification (on the picosecond to nanosecond time scale), this also seems to support the nonthermal nature of the graphitization. We expect that our findings will then contribute to the ongoing discussion on the nature of nonthermal transitions.

The present study is limited to photon energies below the carbon K edge (\(\hbar\omega = 285\) eV). At photon energies higher than the K-edge energy the photoexcitation of core level electrons, and subsequent specific relaxation processes, such as Auger decay, would additionally influence the dynamics of the phase transition. Their specific contribution has to be investigated separately, both experimentally and theoretically.

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